

TÜV MANAGEMENT SERVICE



An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

NPN SILICON PLANAR POWER TRANSISTOR





TO-3 Metal Can Package

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V _{CEO (sus)}	700	V
Collector Emitter Voltage	V _{CES}	1500	V
Emitter Base Voltage	V _{EBO}	5.0	V
Collector Current Continuous	I _C	5.0	A
Peak	I _{CM}	7.5	
Base Current Continuous	I _B	4.0	A
Peak (Negative)	I _{BM}	3.5	
Power Dissipation @ T _c =95°C	P _D	12.5	W
Derate Above 95 ^o C		0.625	W/ºC
Operating and Storage Junction	T _j , T _{stg}	- 65 to +115	ōC
Temperature Range			

THERMAL RESISTANCE

Junction to Case	$R_{th(j-c)}$	1.6	ºC/W
Maximum Lead Temperature for	T_L	275	ºC
Soldering Purpose 1/8" from Case for			
5 Seconds			

ELECTRICAL CHARACTERISTICS (T_C=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	Тур	MAX	UNITS
Collector Emitter Sustaing Voltage	V _{CEO (sus)} *	I _C =100mA, L=25mH	700			V
Collector Cut off Current	I _{CES}	V_{CE} =Rated V_{CES} , V_{BE} =0			1.0	mA
Emitter Base Voltage	V_{EBO}	$I_E=10$ mA, $I_C=0$	5.0			V
		$I_E=100$ mA, $I_C=0$		7.0		
DC Current Gain	h _{FE} *	$I_C=4.5A, V_{CE}=5V$	2.25			
Collector Emitter Saturation Voltage	V _{CE (sat) *}	$I_C=4.5A$, $I_B=2A$			1.0	٧
Base Emitter Saturation Voltage	V _{BE (sat)} *	$I_C=4.5A$, $I_B=2A$			1.5	٧

Dynamic Characteristics

Current Gain Bandwidth Product	f _T	$I_C=0.1A$, $V_{CE}=5V$, $f=1MHz$	4.0	MHz
Output Capacitance	C_ob	$V_{CB}=10V$, $I_{E}=0$, $f=1MHz$	125	pF

Switching Characteristics

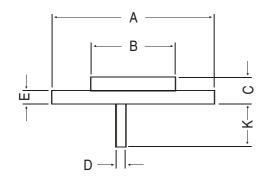
Storage Time	t _S	I _C =4.5A, I _{B1} =1.8A, L _B =10μH	8.0	μs
Fall Time	t _f	$I_C=4.5A$, $I_{B1}=1.8A$, $L_B=10\mu H$	0.4	μs

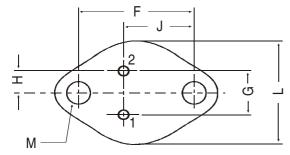
Pulse test: PW=300μs; Duty Cycle<2%

TO-3 Metal Can Package

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All dimensions in mm.





DIM	MIN.	MAX.
Α		39.37
В		22.22
С	6.35	8.50
D	0.96	1.09
Е		1.77
F	29.90	30.40
G	10.69	11.18
Н	5.20	5.72
J	16.64	17.15
K	11.15	12.25
L		26.67
М	3.84	4.19
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PIN CONFIGURATION

- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size Qty		Gr Wt
TO-3	100 pcs/pkt	1.3 kg/100 pcs	12.5" x 8" x 1.8"	0.1K	17" x 11.5" x 21"	2K	27.5 kgs

Notes BU208A

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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